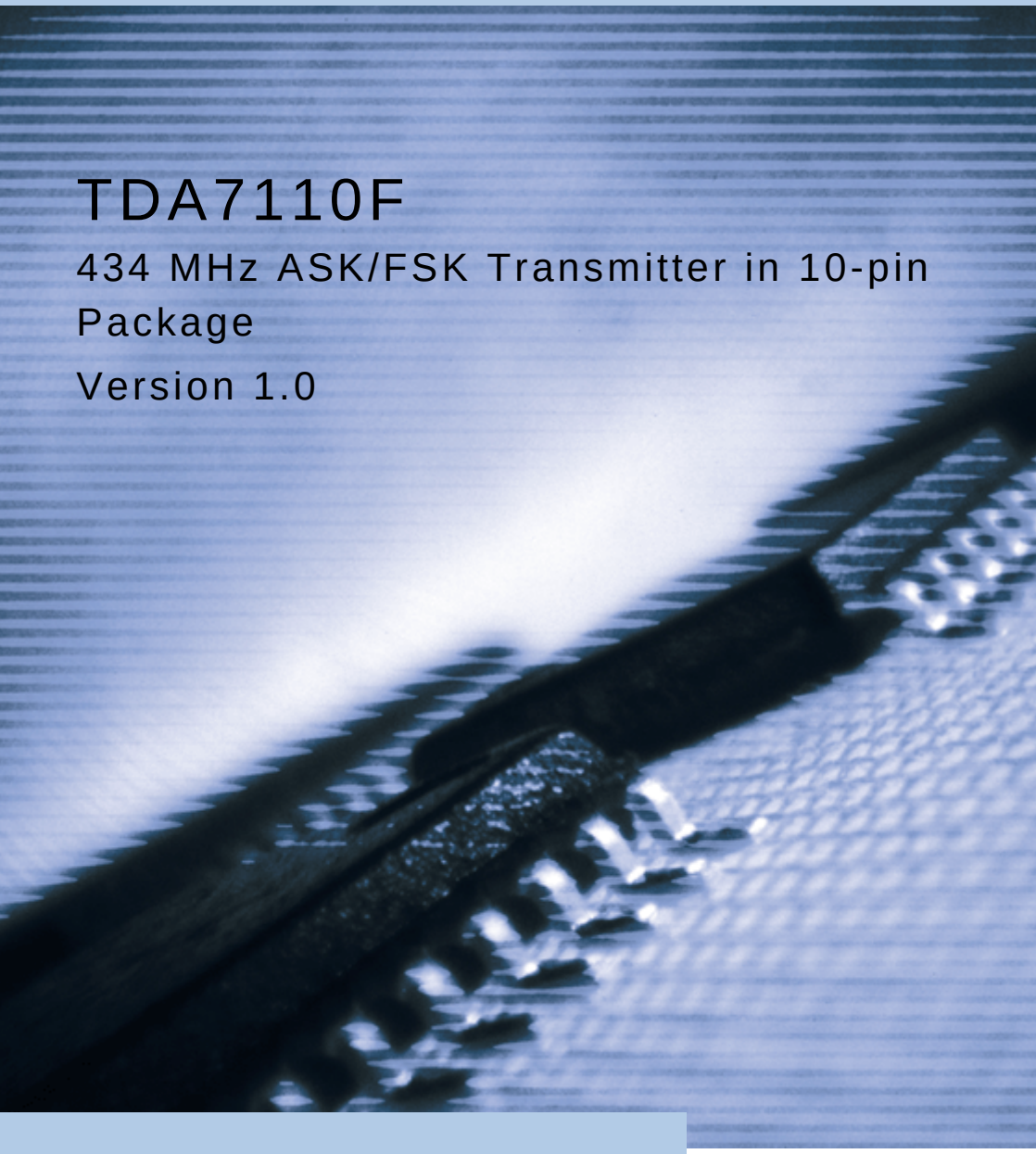


TDA7110F

434 MHz ASK/FSK Transmitter in 10-pin Package

Version 1.0

Wireless Control Components

Never stop thinking.

Edition 2009-02-26

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Revision History:	**2009-02-26**	V 1.0
Previous Version:	none	

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1 Product Description

1.1 Overview

The TDA7110F is a single chip ASK/FSK transmitter for operation in the frequency band 433 ... 435 MHz. The IC offers a high level of integration and needs only a few external components. The device contains a fully integrated PLL synthesizer and a high efficiency power amplifier to drive a loop antenna. A special circuit design and an unique power amplifier design are used to save current consumption and therefore to save battery life. Additional features are a power down mode and a divided clock output.

1.2 Features

- fully integrated frequency synthesizer
- VCO without external components
- ASK and FSK modulation
- frequency range 433 ... 435 MHz
- high efficiency power amplifier (typically 10 dBm)
- low supply current
- voltage supply range 2.1 ... 4 V
- temperature range –40 ... +85°C
- power down mode
- crystal oscillator 13.56 MHz
- FSK-switch
- divided clock output for µC
- low external component count

1.3 Application

- Keyless entry systems
- Remote control systems
- Alarm systems
- Communication systems

1.4 Order Information

Table 1 Order Information

Type	Ordering Code	Package
TDA7110F	SP000611108	PG-TSSOP-10
available on tape and reel		

2 Functional Description

2.1 Pin Configuration

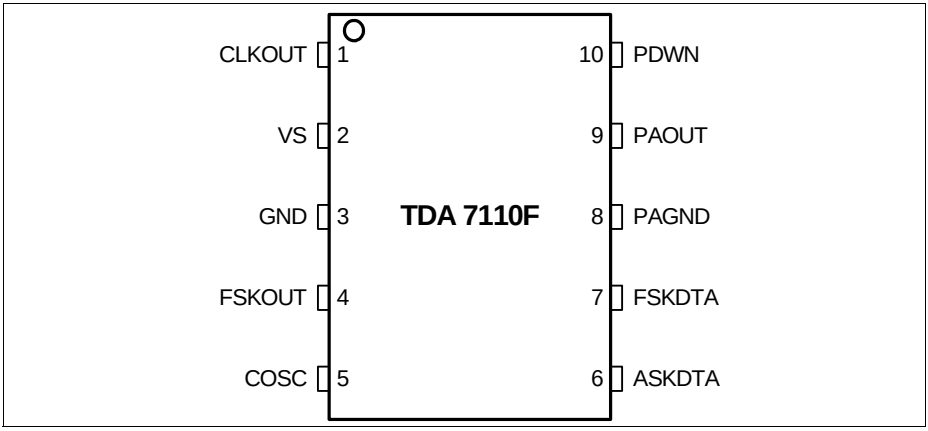


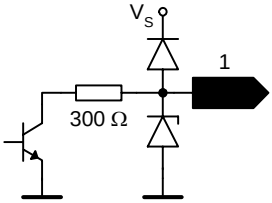
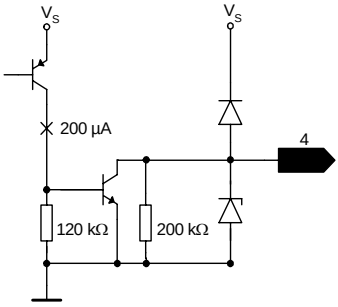
Figure 1 IC Pin Configuration

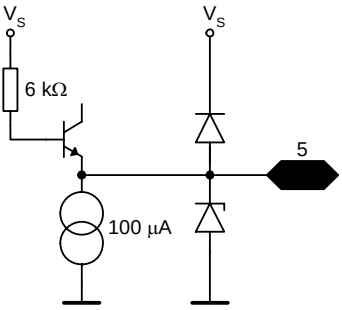
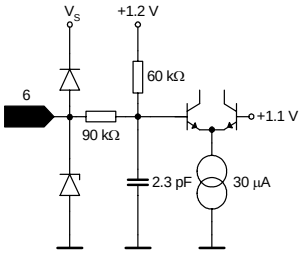
2.2 Pin Definition and Functions

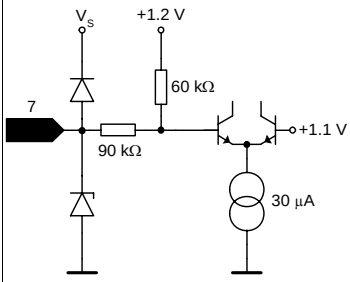
Table 2 Pin Definition and Functions - Overview

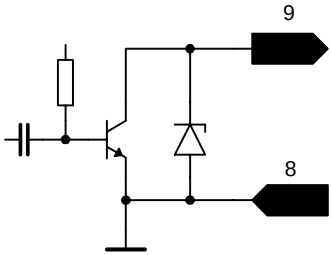
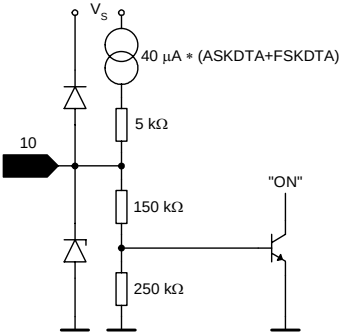
Pin No.	Symbol	Function
1	CLKOUT	Clock Driver Output (847.5 kHz)
2	VS	Voltage Supply
3	GND	Ground
4	FSKOUT	Frequency Shift Keying Switch Output
5	COSC	Crystal Oscillator Input (13.56 MHz)
6	ASKDTA	Amplitude Shift Keying Data Input
7	FSKDTA	Frequency Shift Keying Data Input
8	PAGND	Power Amplifier Ground
9	PAOUT	Power Amplifier Output (434 MHz)
10	PDWN	Power Down Mode Control

Table 3 Pin Definition and Function[1]

Pin No.	Symbol	Interface Schematic	Function
1	CLKOUT		Clock output to supply an external device. An external pull-up resistor has to be added in accordance to the driving requirements of the external device. The clock frequency is 847.5 kHz.
2	VS		This pin is the positive supply of the transmitter electronics. An RF bypass capacitor should be connected directly to this pin and returned to GND (pin 3) as short as possible.
3	GND		General ground connection.
4	FSKOUT		This pin is connected to a switch to GND (pin 3). The switch is closed when the signal at FSKDTA (pin 7) is in a logic low state. The switch is open when the signal at FSKDTA (pin 7) is in a logic high state. FSKOUT can switch an additional capacitor to the reference crystal network to pull the crystal frequency by an amount resulting in the desired FSK frequency shift of the transmitter output frequency.

Pin No.	Symbol	Interface Schematic	Function
5	COSC		This pin is connected to the reference oscillator circuit. The reference oscillator is working as a negative impedance converter. It presents a negative resistance in series to an inductance at the COSC pin.
6	ASKDTA		Digital amplitude modulation can be imparted to the Power Amplifier through this pin. A logic high (ASKDTA > 1.5 V or open) enables the Power Amplifier. A logic low (ASKDTA < 0.5 V) disables the Power Amplifier.

Pin No.	Symbol	Interface Schematic	Function
7	FSKDTA		Digital frequency modulation can be imparted to the Xtal Oscillator by this pin. The VCO-frequency varies in accordance to the frequency of the reference oscillator. A logic high (FSKDTA > 1.5V or open) sets the FSK switch to a high impedance state. A logic low (FSKDTA < 0.5 V) closes the FSK switch from FSKOUT (pin 4) to GND (pin 3). A capacitor can be switched to the reference crystal network this way. The Xtal Oscillator frequency will be shifted giving the designed FSK frequency deviation.

Pin No.	Symbol	Interface Schematic	Function
8	PAGND		Ground connection of the power amplifier. The RF ground return path of the power amplifier output PAOUT (pin 9) has to be concentrated to this pin.
9	PAOUT		RF output pin of the transmitter. A DC path to the positive supply VS has to be supplied by the antenna matching network.
10	PDWN		Disable pin for the complete transmitter circuit. A logic low (PDWN < 0.7 V) turns off all transmitter functions. A logic high (PDWN > 1.5 V) gives access to all transmitter functions. PDWN input will be pulled up by 40 µA internally by either setting FSKDTA or ASKDTA to a logic high-state.

1) Indicated voltages and currents apply for PLL Enable Mode and Transmit Mode.
In Power Down Mode, the values are zero or high-ohmic.

2.3 Functional Block Diagram

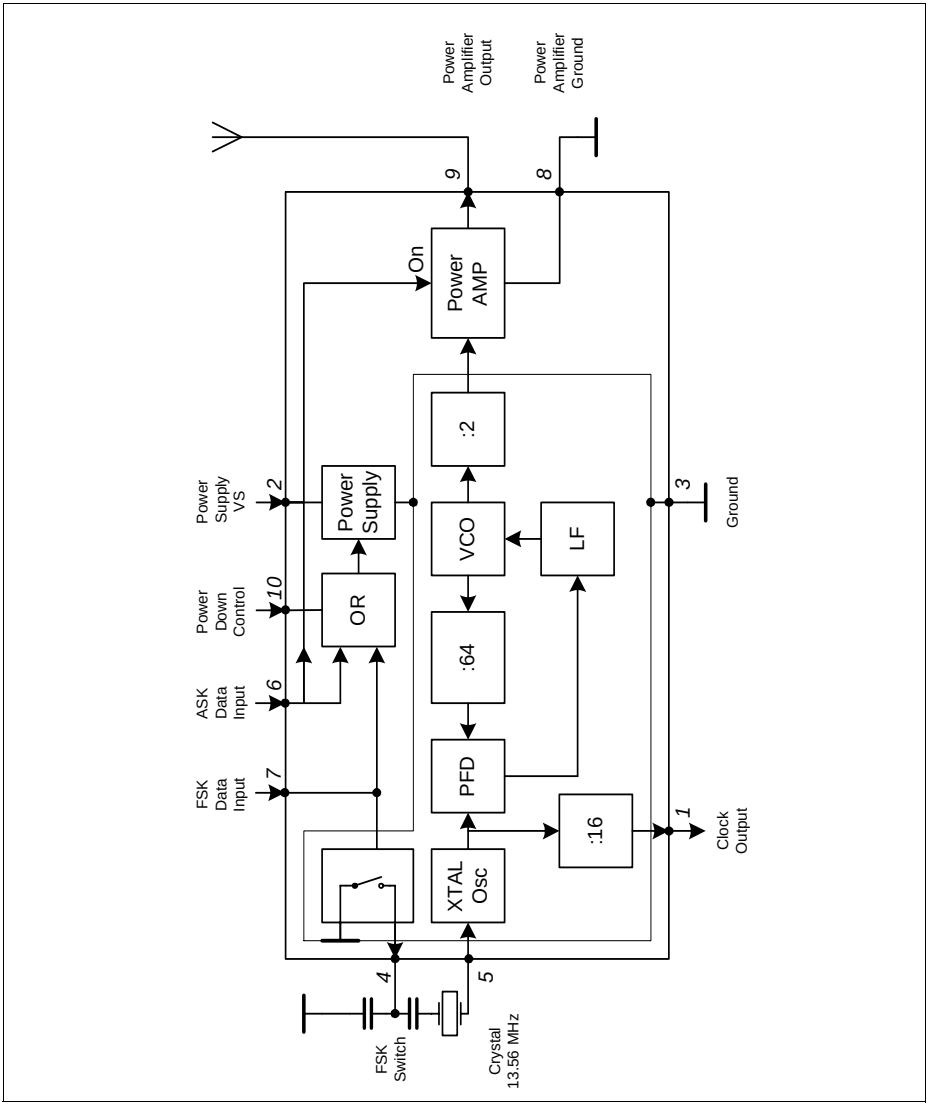


Figure 2 Functional Block Diagram

2.4 Functional Block Description

2.4.1 PLL Synthesizer

The Phase Locked Loop synthesizer consists of a Voltage Controlled Oscillator (VCO), an asynchronous divider chain, a phase detector, a charge pump and a loop filter. It is fully implemented on chip. The tuning circuit of the VCO consisting of spiral inductors and varactor diodes is on chip, too. Therefore no additional external components are necessary. The nominal center frequency of the VCO is 868 MHz. The oscillator signal is fed both, to the synthesizer divider chain and to the power amplifier. The overall division ratio of the asynchronous divider chain is 64. The phase detector is a Type IV PD with charge pump. The passive loop filter is realized on chip.

2.4.2 Crystal Oscillator

The crystal oscillator operates at 13.56 MHz.

The crystal frequency is divided by 16. The resulting 847.5 kHz are available at the clock output CLKOUT (pin1) to drive the clock input of a micro controller.

To achieve FSK transmission, the oscillator frequency can be detuned by a fixed amount by switching an external capacitor via FSKOUT (pin 4).

The condition of the switch is controlled by the signal at FSKDTA (pin 7).

Table 4 FSKDTA - FSK Switch

FSKDTA (pin7)	FSK Switch
Low[1)]	CLOSED
Open[2)], High[3)]	OPEN

1) Low: Voltage at pin < 0.5V

2) Open: Pin open

3) High: Voltage at pin > 1.5V

2.4.3 Power Amplifier

The VCO frequency is divided by 2 and fed to the Power Amplifier.

The Power Amplifier can be switched on and off by the signal at ASKDTA (pin 6).

Table 5 ASKDTA - Power Amplifier

ASKDTA (pin6)	Power Amplifier
Low[1)]	OFF
Open[2)], High[3)]	ON

1) Low: Voltage at pin < 0.5V

2) Open: Pin open

3) High: Voltage at pin > 1.5V

The Power Amplifier has an Open Collector output at PAOUT (pin 9) and requires an external pull-up coil to provide bias. The coil is part of the tuning and matching LC circuitry to get best performance with the external loop antenna. To achieve the best power amplifier efficiency, the high frequency voltage swing at PAOUT (pin 9) should be twice the supply voltage.

The power amplifier has its own ground pin PAGND (pin 8) in order to reduce the amount of coupling to the other circuits.

2.4.4 Power Modes

The IC provides three power modes, the POWER DOWN MODE, the PLL ENABLE MODE and the TRANSMIT MODE.

2.4.4.1 Power Down Mode

In the POWER DOWN MODE the complete chip is switched off.

The current consumption is typically 0.3 nA at 3 V 25°C.

This current doubles every 8°C. The value for higher temperature is typically 14 nA at 85°C.

2.4.4.2 PLL Enable Mode

In the PLL ENABLE MODE the PLL is switched on but the power amplifier is turned off to avoid undesired power radiation during the time the PLL needs to settle. The turn on time of the PLL is determined mainly by the turn on time of the crystal oscillator and is less than 1 msec when the specified crystal is used.

The current consumption is typically 4mA.

2.4.4.3 Transmit Mode

In the TRANSMIT MODE the PLL is switched on and the power amplifier is turned on too.

The current consumption of the IC is typically 14.2 mA when using a proper transforming network at PAOUT, see Figure 8.

2.4.4.4 Power mode control

The bias circuitry is powered up via a voltage V > 1.5 V at the pin PDWN (pin10).
When the bias circuitry is powered up, the pins ASKDTA and FSKDTA are pulled up internally.
Forcing the voltage at the pins low overrides the internally set state.

Alternatively, if the voltage at ASKDTA or FSKDTA is forced high externally, the PDWN pin is pulled up internally via a current source. In this case, it is not necessary to connect the PDWN pin, it is recommended to leave it open.

The principle schematic of the power mode control circuitry is shown in Figure 3

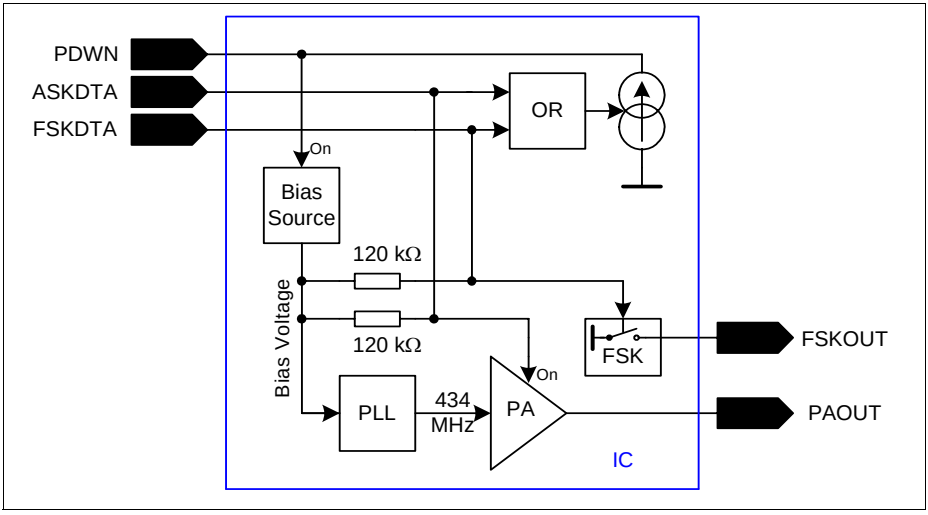


Figure 3 Power mode control circuitry

Table 6 provides a listing of how to get into the different power modes

Table 6 Power Modes

PDWN	FSKDTA	ASKDTA	MODE
Low[1)]	Low, Open	Low, Open	POWER DOWN
Open[2)]	Low	Low	
High[3)]	Low, Open, High	Low	PLL ENABLE
Open	High	Low	
High	Low, Open, High	Open, High	TRANSMIT
Open	High	Open, High	
Open	Low, Open, High	High	

1) Low: Voltage at pin < 0.7V (PDWN)
Voltage at pin < 0.5V (FSKDTA, ASKDTA)

2) Open: Pin open

3) High: Voltage at pin > 1.5V

Other combinations of the control pins PDWN, FSKDTA and ASKDTA are not recommended.

2.4.5 Recommended Timing Diagrams for ASK- and FSK-Modulation

ASK Modulation using FSKDTA and ASKDTA, PDWN not connected

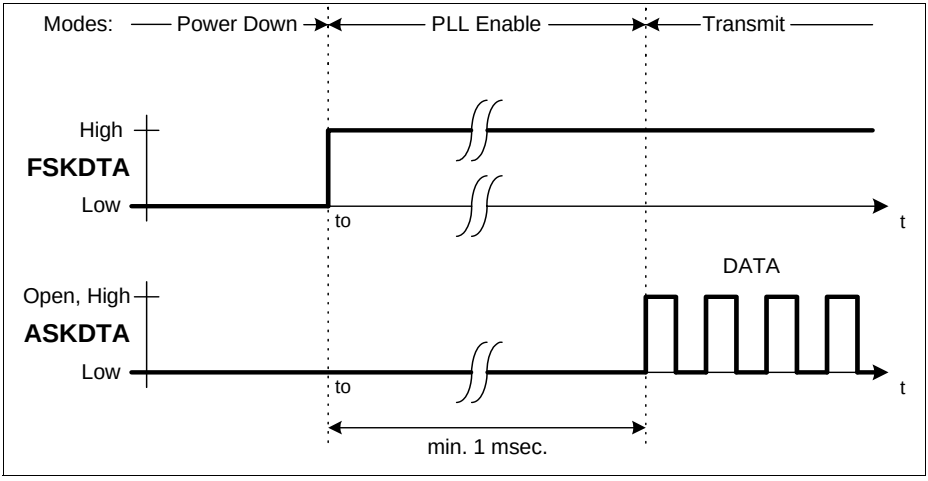


Figure 4 ASK Modulation

FSK Modulation using FSKDTA and ASKDTA, PDWN not connected.

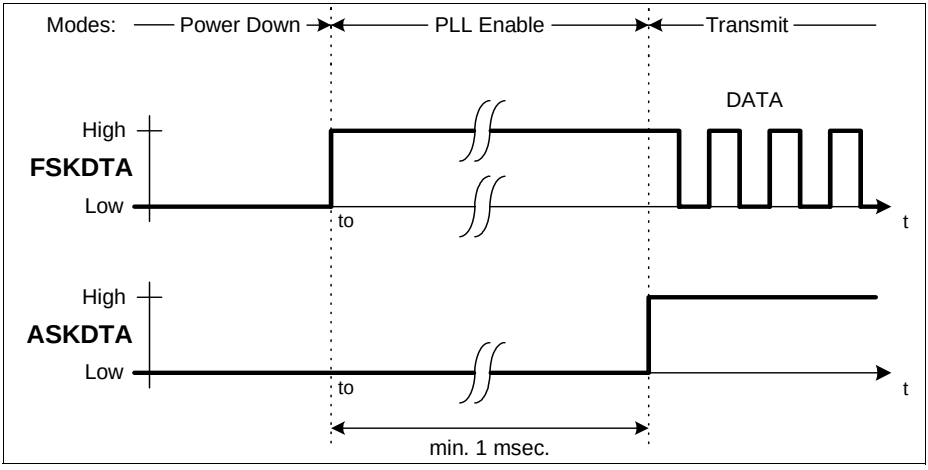


Figure 5 FSK Modulation

Alternative ASK Modulation, FSKDTA not connected.

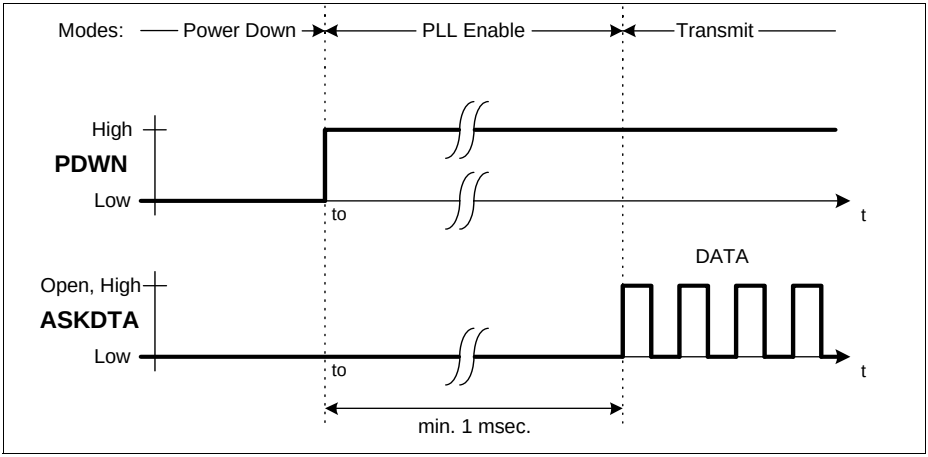


Figure 6 Alternative ASK Modulation

Alternative FSK Modulation

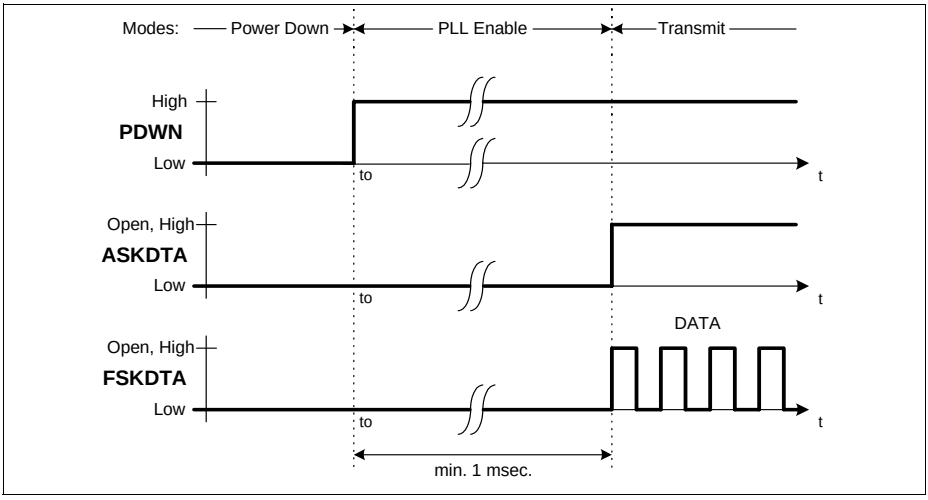


Figure 7 Alternative FSK Modulation

3 Applications

3.1 50 Ohm-Output Testboard Schematic

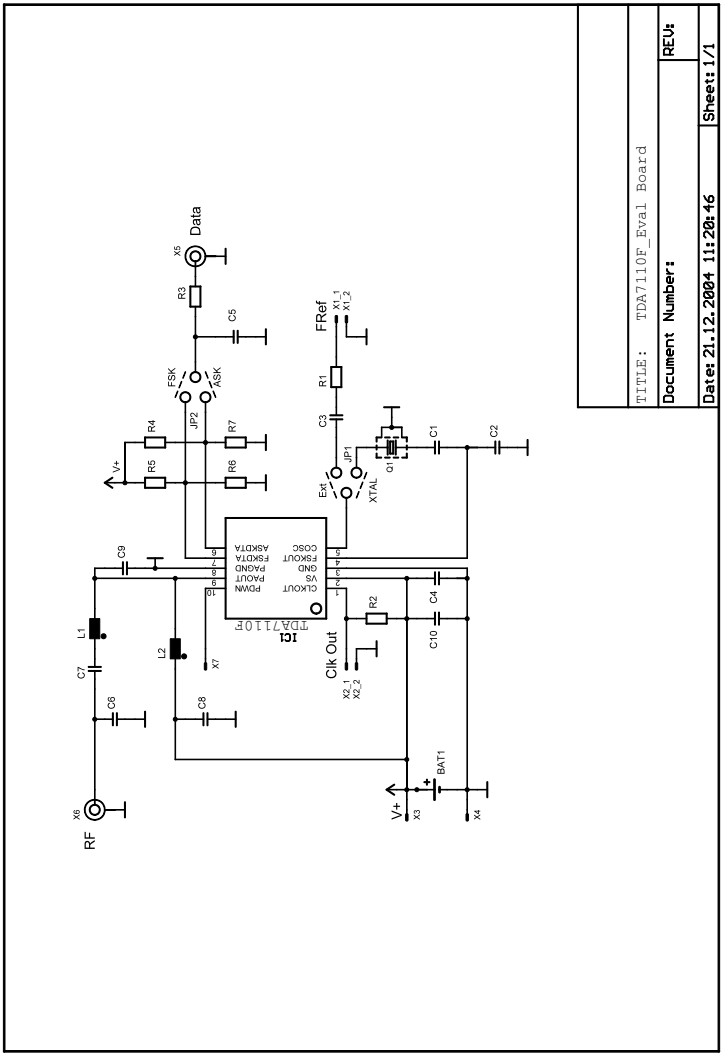


Figure 8 50 Ohm-output testboard schematic

3.2 50 Ohm-Output Testboard Layout

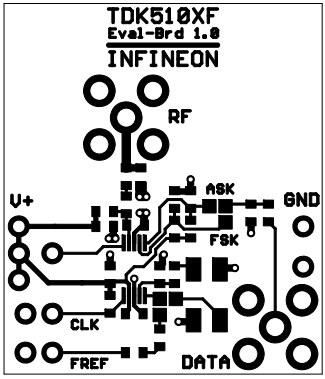


Figure 9 Top Side of TDA7110F-Testboard[1] with 50 Ohm-Output

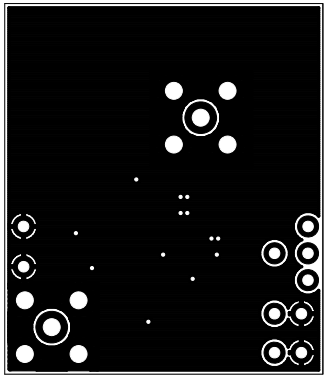


Figure 10 Bottom Side of TDA7110F-Testboard[1] with 50 Ohm-Output

1) Name and labeling of the PCB itself is TDK510xF

3.3 Bill of Material (50 Ohm-Output Evalboard)

Reference	Value	Specification
R1	open	
R2	open	
R3	4k7	0603, +/-5%
R4	12k	0603, +/-5%
R5	open	
R6	15k	0603, +/-5%
R7	open	
C1	10p	0603, C0G, +/-1%
C2	6p8	0603, C0G, +/-0.1p
C3	open	
C4	open	
C5	100p	0603, X7R, +/-10%
C6	10p	0603, C0G, +/-1%
C7	39p	0603, C0G, +/-1%
C8	1n	0603, C0G, +/-5%
C9	3p9	0603, C0G, +/-0.1p
C10	47n	0603, X7R, +/-10%
L1	39n	EPCOS SIMID 0603-C, +/-2%
L2	100n	EPCOS SIMID 0603-C, +/-2%
X1	n.e.	
X2	n.e.	
X3	Pin	single-pole connector, 2.54 mm
X4	Pin	single-pole connector, 2.54 mm
X5	SMA-connector	
X6	SMA-connector	
X7	n.e.	
JP1	solder bridge	in position “XTAL”
JP2	solder bridge	in position “FSK”
Q1	13.56875 MHz, CL=12pF	Tokyo Denpa TSS-3B 13.56875 MHz Spec. No. 10-50205
IC1	TDA7110F	

3.4 Application Hints on the Crystal Oscillator

Application Hints on the crystal oscillator

The crystal oscillator achieves a turn on time less than 1 msec when the specified crystal is used. To achieve this, a NIC oscillator type is implemented in the TDA7110F. The input impedance of this oscillator is a negative resistance in series to an inductance. Therefore the load capacitance of the crystal CL (specified by the crystal supplier) is transformed to the capacitance Cv.

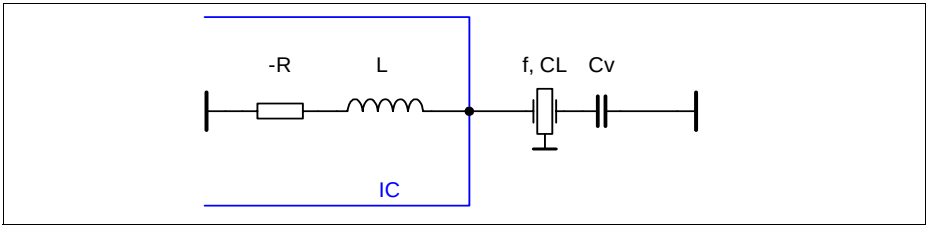


Figure 11 Application Hints

Formula 1:

$$Cv = \frac{1}{\frac{1}{CL} + \omega^2 L}$$

CL: crystal load capacitance for nominal frequency
ω: angular frequency
L: inductance of the crystal oscillator

Example for the ASK-Mode:

Referring to the application circuit, in ASK-Mode the capacitance C2 is replaced by a short to ground. Assume a crystal frequency of 13.56MHz and a crystal load capacitance of CL = 12 pF. The inductance L at 13.56MHz is about 4.6 µH. Therefore C1 is calculated to 10 pF.
But please note that the calculated Cv value includes all parasitic. So the value of the capacitor (except the parasitic) is a bit smaller depending on the parasitic.

$$Cv = \frac{1}{\frac{1}{CL} + \omega^2 L} = C1$$

Example for the FSK-Mode:

FSK modulation is achieved by switching the load capacitance of the crystal as shown below.

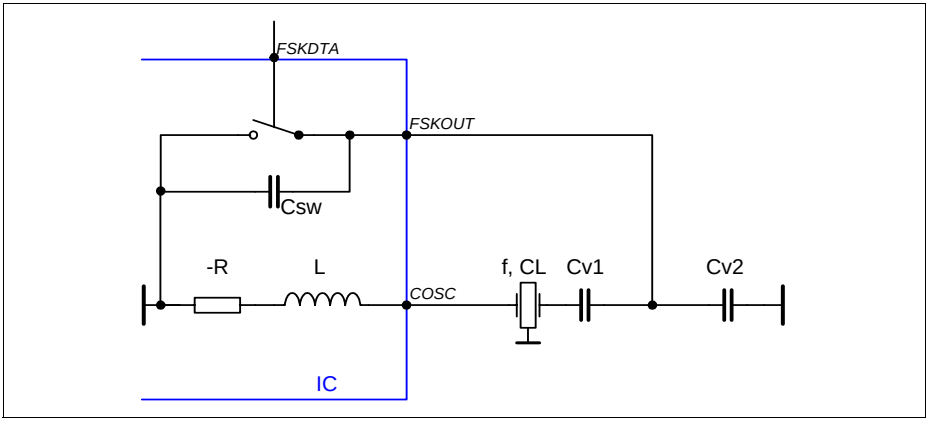


Figure 12 FSK Mode

The frequency deviation of the crystal oscillator is multiplied with the divider factor N of the Phase Locked Loop to the output of the power amplifier. In case of small frequency deviations (up to +/- 1000 ppm), the two desired load capacitances can be calculated with the formula below.

$$CL\pm = \frac{CL \mp C0\frac{\Delta f}{N * f1}(1+\frac{2(C0+CL)}{C1})}{1\pm\frac{\Delta f}{N * f1}(1+\frac{2(C0+CL)}{C1})}$$

C_L: crystal load capacitance for nominal frequency

C_0: shunt capacitance of the crystal

f: frequency

ω: $\omega = 2\pi f$: angular frequency

N: division ratio of the PLL

df: peak frequency deviation

Because of the inductive part of the TDA7110F, these values must be corrected by Formula 1 on the preceding page. The value of Cv± can be calculated.

$$Cv\pm = \frac{1}{\frac{1}{CL\pm} + \omega^2 L}$$

If the FSK switch is closed, Cv± is equal to Cv1 (C1 in the application diagram). If the FSK switch is open, Cv2 (C2 in the application diagram) can be calculated.

$$Cv2 = C2 = \frac{Csw * Cv1 - (Cv+) * (Cv1 + Csw)}{(Cv+) - Cv1}$$

Csw: parallel capacitance of the FSK switch (3 pF incl. layout parasitics)

Remark: These calculations are only approximations. The necessary values depend on the parasitic and thus on the layout also and must be adapted for the specific application board.

3.5 Design Hints on the Clock Output (CLKOUT)

The CLKOUT pin is an open collector output. An external pull up resistor (RL) should be connected between this pin and the positive supply voltage. The value of RL is depending on the clock frequency and the load capacitance CLD (PCB board plus input capacitance of the microcontroller). RL can be calculated to:

$$RL = \frac{1}{fCLKOUT * 8 * CLD}$$

Table 7 Clock Output

fCLKOUT=847.5 kHz	
CL[pF]	RL[kOhm]
5	27
10	12
20	6.8

Remark: To achieve a low current consumption and a low spurious radiation, the largest possible RL should be chosen.

Even harmonics of the signal at CLKOUT can interact with the crystal oscillator input COSC preventing the start-up of oscillation. Care must be taken in layout by sufficient separation of the signal lines to ensure sufficiently small coupling.

3.6 Application Hints on the Power-Amplifier

The power amplifier operates in a high efficient class C mode. This mode is characterized by a pulsed operation of the power amplifier transistor at a current flow angle of $\theta << \pi$. A frequency selective network at the amplifier output passes the fundamental frequency component of the pulse spectrum of the collector current to the load. The load and its resonance transformation to the collector of the power amplifier can be generalized by the equivalent circuit of Figure 13. The tank circuit L//C//RL in parallel to the output impedance of the transistor should be in resonance at the operating frequency of the transmitter.

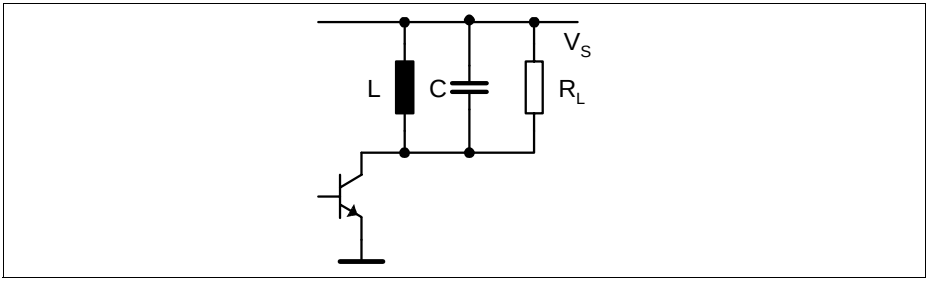


Figure 13 Equivalent power amplifier tank circuit

The optimum load at the collector of the power amplifier for “critical” operation under idealized conditions at resonance is:

$$R_{LC} = \frac{V_S^2}{2 * P_O}$$

The theoretical value of R_{LC} for an RF output power of P_o= 10dBm (10mW) is:

$$R_{LC} = \frac{3^2}{2 * 0.01} = 450\Omega$$

“Critical” operation is characterized by the RF peak voltage swing at the collector of the PA transistor to just reach the supply voltage V_S.
The high degree of efficiency under “critical” operating conditions can be explained by the low power losses at the transistor. During the conducting phase of the transistor, its collector voltage is very small. This way the power loss of the transistor, equal to $i_C * u_{CE}$ is minimized. This is particularly true for small current flow angles of $\theta << \pi$.

In practice the RF-saturation voltage of the PA transistor and other parasitics reduce the "critical" R_{LC}.

The output power P_o is reduced by operating in an "overcritical" mode characterised by $R_L > R_{LC}$.

The power efficiency (and the bandwidth) increase when operating at a slightly higher R_L, as shown in Figure 14.

The collector efficiency E is defined as

$$E = \frac{P_O}{V_S I_C}$$

The diagram of Figure 14 was measured directly at the PA-output at V_S = 3 V. Losses in the matching circuitry decrease the output power by about 1.5 dB. As can be seen from the diagram, 250 Ω is the optimum impedance for operation at 3 V. For an approximation of R_{OPT} and P_{OUT} at other supply voltages those two formulas can be used:

$$R_{OPT} \sim V_S$$

and

$$P_{OUT} \sim R_{OPT}$$

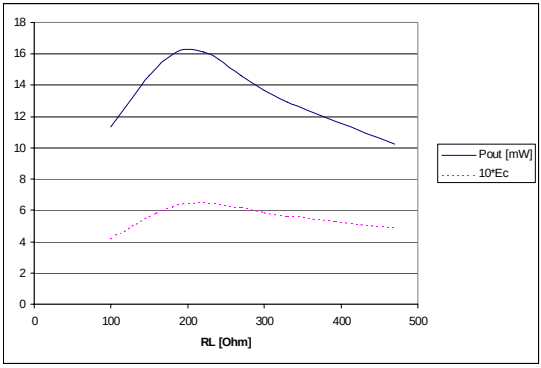


Figure 14 Output power P_o (mW) and collector efficiency E vs. load resistor R_L.

The DC collector current I_c of the power amplifier and the RF output power P_o vary with the load resistor R_L. This is typical for overcritical operation of class C amplifiers. The collector current will show a characteristic dip at the resonance frequency for this type of "overcritical" operation. The depth of this dip will increase with higher values of R_L.

4 Reference

4.1 Electrical Data

4.1.1 Absolute Maximum Ratings

Attention: The maximum ratings must not be exceeded under any circumstances, not even momentarily and individually, as permanent damage to the IC will result.

Table 8 Absolute Maximum Ratings, T_{amb} = -40 °C … +85 °C

Parameter	Symbol	Limit Values		Unit	Remarks
		min.	max.		
Junction Temperature	T_J	–40	+150	°C	
Storage Temperature	T_s	–40	+125	°C	
Thermal Resistance	R_{thJA}		220	K/W	
Supply voltage	V_S	–0.3	+4.0	V	
Voltage at any pin excluding pin 9	V_{pins}	-0.3	V_S + 0.3	V	
Voltage at pin 9	V_{pin9}	-0.3	2 * V_S	V	No ESD-Diode to V_S
ESD integrity, all pins	V_{ESD}	-1	+1	kV	JEDEC Standard JESD22-A114-B
ESD integrity, all pins excluding pin 9	V_{ESD}	-2.5	+2.5	kV	JEDEC Standard JESD22-A114-B

Ambient Temperature under bias: T_A = –40°C to +85°C

Note: All voltages referred to ground (pins) unless stated otherwise.

Pins 3 and 8 are grounded.

4.2 Operating Ratings

Within the operational range the IC operates as described in the circuit description.

Table 9 Operating Ratings

Parameter	Symbol	Limit Values		Unit	Test Conditions
		min.	max.		
Supply voltage	V_S	2.1	4.0	V	
Ambient temperature	T_A	-40	85	°C	

4.3 AC/DC Characteristics

AC/DC characteristics involve the spread of values guaranteed within the specified supply voltage and ambient temperature. Typical charcateristics are the median of the production.

4.3.1 AC/DC Characteristic at 3V, 25°C

Table 10 Supply Voltage V_S=3V, Ambient temperature T_{amb}=25°C

Parameter	Symbol	Limit Values			Unit	Test Conditions
		min.	typ.	max.		
Current consumption						
Power Down mode	$I_{S\ PDWN}$		0.3	100	nA	V (Pins 10, 6 and 7) < 0.2 V
PLL Enable mode	$I_{S\ PLL_EN}$		4	5.5	mA	
Transmit mode 434 MHz	$I_{S\ TRANSM}$		14.2	18	mA	
Output frequency						
Output frequency	f_{OUT}	427	434.5	442	MHz	$f_{OUT} = 32 * f_{COSC}$
Clock Driver Output (Pin 1)						
Output current (High)	I_{CLKOUT}			5	µA	$V_{CLKOUT} = V_S$
Saturation Voltage (Low)[1)]	V_{SATL}			0.56	V	I_{CLKOUT} = 1 mA

Table 10 Supply Voltage V_S=3V, Ambient temperature T_{amb}=25°C (cont'd)

Parameter	Symbol	Limit Values			Unit	Test Conditions
		min.	typ.	max.		
FSK Switch Output (Pin 4)						
On resistance	R_{FSKOUT}			250	Ω	V_{FSKDTA} = 0 V
On capacitance	C_{FSKOUT}			6	pF	V_{FSKDTA} = 0 V
Off resistance	R_{FSKOUT}	10			kΩ	V_{FSKDTA} = V_S
Off capacitance	C_{FSKOUT}			1.5	pF	V_{FSKDTA} = V_S
Crystal Oscillator Input (Pin 5)						
Load capacitance	$C_{COSCmax}$			5	pF	
Serial Resistance of the crystal				100	Ω	f = 13.56 MHz
Input inductance of the COSC pin			4.6		µH	f = 13.56 MHz
ASK Modulation Data Input (Pin 6)						
ASK Transmit disabled	V_{ASKDTA}	0		0.5	V	
ASK Transmit enabled	V_{ASKDTA}	1.5		V_S	V	
Input bias current ASKDTA	I_{ASKDTA}			30	µA	V_{ASKDTA} = V_S
Input bias current ASKDTA	I_{ASKDTA}	-20			µA	V_{ASKDTA} = 0 V
ASK data rate	f_{ASKDTA}			20	kHz	
FSK Modulation Data Input (Pin 7)						
FSK Switch on	V_{FSKDTA}	0		0.5	V	
FSK Switch off	V_{FSKDTA}	1.5		V_S	V	
Input bias current FSKDTA	I_{FSKDTA}			30	µA	V_{FSKDTA} = V_S
Input bias current FSKDTA	I_{FSKDTA}	-20			µA	V_{FSKDTA} = 0 V
FSK data rate	f_{FSKDTA}			20	kHz	
Power Amplifier Output (Pin 9)						
Output Power[2)] at 434 MHz transformed to 50 Ohm	P_{OUT434}	7	10	13	dBm	

Table 10 Supply Voltage V_S=3V, Ambient temperature T_{amb}=25°C (cont'd)

Parameter	Symbol	Limit Values			Unit	Test Conditions
		min.	typ.	max.		
Power Down Mode Control (Pin 10)						
Power Down mode	V_{PDWN}	0		0.7	V	V_{ASKDTA} < 0.2 V V_{FSKDTA} < 0.2 V
PLL Enable mode	V_{PDWN}	1.5		V_S	V	V_{ASKDTA} < 0.5 V
Transmit mode	V_{PDWN}	1.5		V_S	V	V_{ASKDTA} > 1.5 V
Input bias current PDWN	I_{PDWN}			30	µA	$V_{PDWN} = V_S$

1) Derating linearly to a saturation voltage of max. 140 mV at I_{CLKOUT} = 0 mA

2) Power amplifier in overcritical C-operation
Matching circuitry as used in the 50 Ohm-Output Testboard at the specified frequency.
Tolerances of the passive elements not taken into account.

4.3.2 AC/DC Characteristic at 2.1V ... 4.0 V, -40°C ...+85°C

Table 11 Supply Voltage V_S=2.1V ... 4.0V, T_{amb}=-40°C ... +85°C

Parameter	Symbol	Limit Values			Unit	Test Conditions
		min.	typ.	max.		
Current consumption						
Power Down mode	$I_{S\ PDWN}$			4	µA	V (Pins 10, 6 and 7) < 0.2 V
PLL Enable mode	$I_{S\ PLL_EN}$	2.5	4	6	mA	
Transmit mode Load tank see Figure 8 and 9	$I_{S\ TRANSM}$		11	15.5	mA	V_S = 2.1 V
	$I_{S\ TRANSM}$		14.2	18	mA	V_S = 3.0 V
	$I_{S\ TRANSM}$		16.2	21	mA	V_S = 4.0 V
Output frequency						
Output frequency[1)]	f_{OUT}	432	434.5	437	MHz	$f_{OUT} = 32 * f_{COSC}$
Clock Driver Output (Pin 1)						
Output current (High)	I_{CLKOUT}			5	µA	$V_{CLKOUT} = V_S$
Saturation Voltage (Low)[2)]	V_{SATL}			0.5	V	I_{CLKOUT} = 0.6 mA

Table 11 Supply Voltage V_S=2.1V ... 4.0V, T_{amb}=-40°C ... +85°C (cont'd)

Parameter	Symbol	Limit Values			Unit	Test Conditions
		min.	typ.	max.		
FSK Switch Output (Pin 4)						
On resistance	R_{FSKOUT}			280	Ω	V_{FSKDTA} = 0 V
On capacitance	C_{FSKOUT}			6	pF	V_{FSKDTA} = 0 V
Off resistance	R_{FSKOUT}	10			kΩ	V_{FSKDTA} = V_S
Off capacitance	C_{FSKOUT}			1.5	pF	V_{FSKDTA} = V_S
Crystal Oscillator Input (Pin 5)						
Load capacitance	$C_{COSCmax}$			5	pF	
Serial Resistance of the crystal				100	Ω	f = 13.56 MHz
Input inductance of the COSC pin			4.6		µH	f = 13.56 MHz
ASK Modulation Data Input (Pin 6)						
ASK Transmit disabled	V_{ASKDTA}	0		0.5	V	
ASK Transmit enabled	V_{ASKDTA}	1.5		V_S	V	
Input bias current ASKDTA	I_{ASKDTA}			33	µA	V_{ASKDTA} = V_S
Input bias current ASKDTA	I_{ASKDTA}	-20			µA	V_{ASKDTA} = 0 V
ASK data rate	f_{ASKDTA}			20	kHz	
FSK Modulation Data Input (Pin 7)						
FSK Switch on	V_{FSKDTA}	0		0.5	V	
FSK Switch off	V_{FSKDTA}	1.5		V_S	V	
Input bias current FSKDTA	I_{FSKDTA}			33	µA	V_{FSKDTA} = V_S
Input bias current FSKDTA	I_{FSKDTA}	-20			µA	V_{FSKDTA} = 0 V
FSK data rate	f_{FSKDTA}			20	kHz	

Table 11 Supply Voltage V_S=2.1V ... 4.0V, T_{amb}=-40°C ... +85°C (cont'd)

Parameter	Symbol	Limit Values			Unit	Test Conditions
		min.	typ.	max.		
Power Amplifier Output (Pin 9)						
Output Power [3] at 434 MHz transformed to 50 Ohm.	$P_{OUT, 434}$	4	6.5	9.5	dBm	V_S = 2.1 V
	$P_{OUT, 434}$	6	10	13	dBm	V_S = 3.0 V
	$P_{OUT, 434}$	6.5	11.5	16	dBm	V_S = 4.0 V
Power Down Mode Control (Pin 10)						
Power Down mode	V_{PDWN}	0		0.5	V	V_{ASKDTA} < 0.2 V V_{FSKDTA} < 0.2 V
PLL Enable mode	V_{PDWN}	1.5		V_S	V	V_{ASKDTA} < 0.5 V
Transmit mode	V_{PDWN}	1.5		V_S	V	V_{ASKDTA} > 1.5 V
Input bias current PDWN	I_{PDWN}			38	µA	V_{PDWN} = V_S

1) a) When the minimum T_A is increased by 5°C, the minimum f_{VCO} decreases by 1 MHz.

b) When the maximum T_A is decreased by 5°C, the maximum f_{VCO} increases by 1 MHz.

c) When the minimum V_S is increased by 25 mV, the maximum f_{VCO} increases by 1 MHz.
Restriction of c): The maximum f_{VCO} must not be increased by more than 40 MHz by increasing V_S.

Please note that f_{VCO} is twice the Output Frequency.

All three measures can be taken independently and additive.

2) Derating linearly to a saturation voltage of max. 140 mV at I_{CLKOUT} = 0 mA

3) Matching circuitry as used in the 50 Ohm-Output Testboard.

Tolerances of the passive elements not taken into account.

Range @ 2.1 V, +25°C: 6.5 dBm +/- 2 dBm

Range @ 3.0 V, +25°C: 10 dBm +/- 3 dBm

Range @ 4.0 V, +25°C: 11.5 dBm +4.5/-3.5 dBm

5 Package Outlines

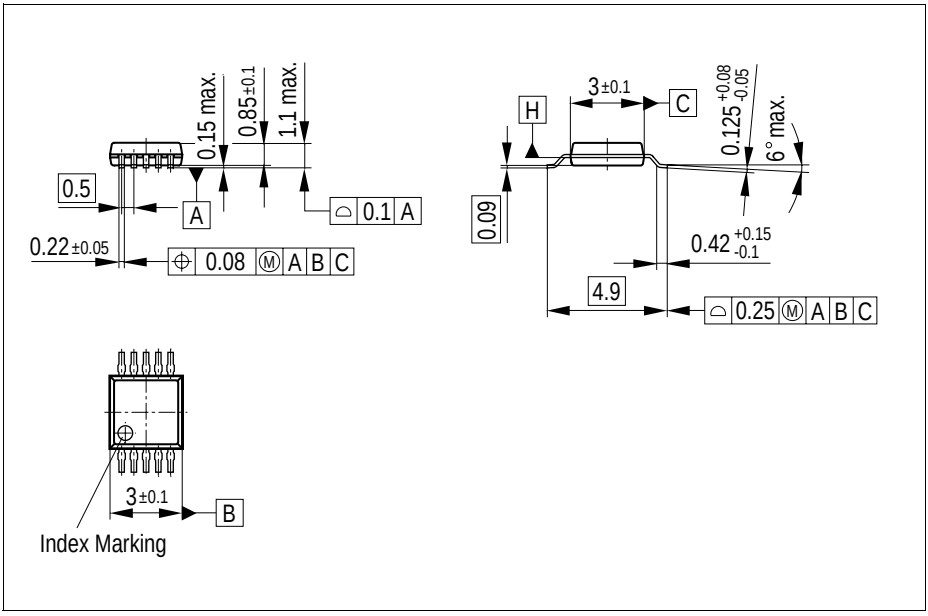


Figure 15 PG-TSSOP-10

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SMD = Surface Mounted Device

Dimensions in mm

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